imall

Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from, Europe, America and south Asia, supplying obsolete and hard-to-find components to meet their specific needs.

With the principle of "Quality Parts, Customers Priority, Honest Operation, and Considerate Service", our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip, ALPS, ROHM, Xilinx, Pulse, ON, Everlight and Freescale. Main products comprise IC, Modules, Potentiometer, IC Socket, Relay, Connector. Our parts cover such applications as commercial, industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



Contact us

Tel: +86-755-8981 8866 Fax: +86-755-8427 6832 Email & Skype: info@chipsmall.com Web: www.chipsmall.com Address: A1208, Overseas Decoration Building, #122 Zhenhua RD., Futian, Shenzhen, China







DIMMABLE LED DRIVER

Description

The AL1692-10E is a high performance, high power factor, high efficiency, and high current precision buck-boost and flyback dimmable LED driver for triac dimmable LED lamp applications. The AL1692-10E topology provides an accurate output current over wide line and load regulation. The wide switching frequency operates at boundary conduction mode (BCM) to ease EMI/EMC design and testing to meet the latest regulatory standards.

The AL1692-10E LED driver integrates a 700V/1A high voltage MOSFET. It can cover both 120Vac and 230Vac triac dimmable applications with eliminating the external high voltage MOSFET and Varistor, which will reduce the system BOM cost. The AL1692-10E has the built-in thermal fold-back protection trigger point to automatically reduce output current. Other protection features enhance LED lighting system's safety and reliability.

The AL1692-10E dimming curve is compliant with the NEMA SSL6 standard. The AL1692-10E applies to a wide range of dimmers, including leading edge and trailing edge dimmer, to achieve deep dimming down to 1%

The AL1692-10E is available in SO-7 package.

Features

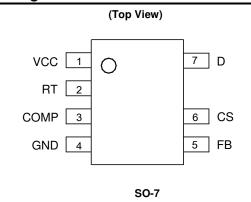
- Tight Current Sense Tolerance : ± 3%
- Low Startup Current: 100µA Typical
- Low Operation Current: 210µA (Switching Frequency at 4kHz)
- Single Winding Inductor
- Wide Range of Dimmer Compatibility
- Integration of 700V/1A MOSFET
- NEMA SSL6 Dimming Curve Compliant
- Internal Protections
 - Under Voltage Lockout (UVLO)
 - Leading-Edge Blanking (LEB)
 - Cycle-By-Cycle Over Current Protection (OCP)
 - Output Open/Short Protection (OVP/OSP)
 - Thermal Foldback Protection (TFP)
 - Over-Temperature Protection (OTP)
- SO-7 Package
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)

Notes:

1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.

- 2. See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

Pin Assignments

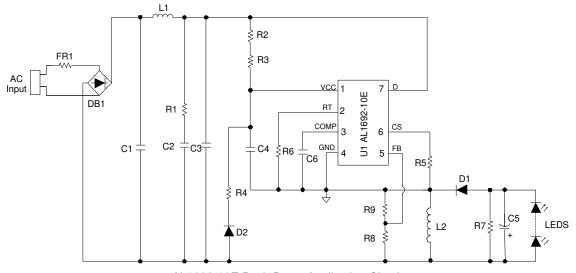


Applications

- Mains Dimmable LED Lamps
- Offline LED Power Supply Driver



Typical Application Circuits



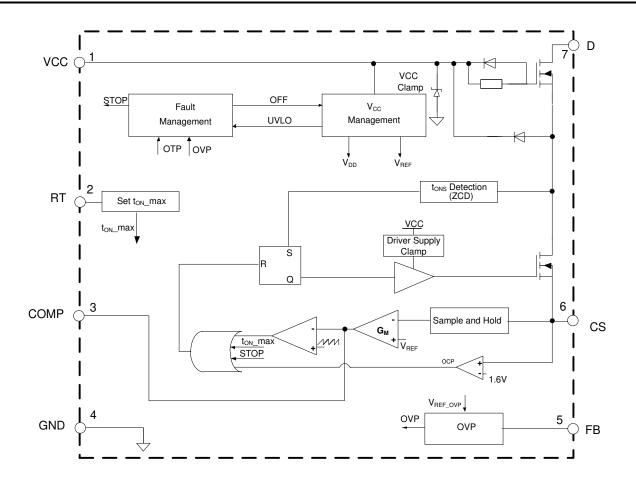
AL1692-10E Buck-Boost Application Circuit

Pin Descriptions

Pin Number	Pin Name	Function			
1	VCC	Power supply voltage			
2	RT	Resistor set the system's maximum t _{ON}			
3	COMP	Compensation for current control			
4	GND	Ground			
5	FB	Feedback for LED open protection voltage			
6	CS	Current sensing			
7	D	Drain of the internal high voltage MOSFET			



Functional Block Diagram



AL1692-10E Block Diagram

NEW PRODUCT



Absolute Maximum Ratings (@T_A = +25°C, unless otherwise specified.) (Note 4)

Symbol	Parameter	Rating	Unit
V _{CC}	Power Supply Voltage	18	V
VD	Voltage on Drain Pin	700	V
IDS	Continuous Drain Current T _C = +25°C	1	А
V _{CS}	Voltage on CS Pin	-0.3 to 7	V
V _{RT}	Voltage on RT Pin	-0.3 to 7	V
V _{FB}	Voltage on FB Pin	-0.3 to 7	V
TJ	Operating Junction Temperature	-40 to +150	°C
T _{STG}	Storage Temperature	-65 to +150	°C
T _{LEAD}	Lead Temperature (Soldering, 10 seconds)	+260	°C
PD	Power Dissipation ($T_A = +50^{\circ}C$) (Note 5)	0.8	W
$ heta_{JA}$	Thermal Resistance (Junction to Ambient) (Note 5)	123	°C/W
θJC	Thermal Resistance (Junction to Case) (Note 5)	19	°C/W
_	– ESD (Human Body Model)		V

Notes: 4. Stresses greater than those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "Recommended Operating Conditions" is not implied. Exposure to "Absolute Maximum Ratings" for extended periods may affect device reliability. All voltages unless otherwise stated and measured with respect to GND.

5. Device mounted on 1"x1" FR-4 substrate PCB, 2oz copper, with minimum recommended pad layout.

Recommended Operating Conditions (@T_A = +25°C, unless otherwise specified.)

Symbol	Parameter	Min	Мах	Unit
T _A	Ambient Temperature (Note 6)	-40	+105	°C
V _{CC}	Operating V _{CC} Voltage	10	V _{CC_CLAMP} (Min)	V

Note: 6. The device may operate normally at +125°C ambient temperature under the condition not trigger temperature protection.



Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Symbol	Parameter	Condition	Min	Тур	Max	Unit
UVLO						
V _{TH (ST)}	Startup Voltage	-	_	14.5	-	V
V _{OPR(MIN)}	Minimal Operating Voltage	After Turn On	-	8.5	-	V
V _{CC_CLAMP}	V _{CC} Clamp Voltage	I _{CC} = 1mA	14	15.5	-	V
Standby Current			•			
I _{ST}	Start-Up Current	$V_{CC} = V_{TH (ST)}$ -0.5V, Before Start Up	_	100	_	μΑ
I _{CC (OPR)}	Operating Current	Switching Frequency at 4kHz	_	210	-	μA
Source Driver			1			
Rds(on)_LV	Internal Low Voltage MOSFET On- State Resistance (Note 7)	-	_	1	_	Ω
High Voltage and Supe	er-Junction MOSFET			-		
R _{DS(ON)} _HV	Drain-Source On-State Resistance	_	_	8.8	10.5	Ω
V _{DS}	Drain-Source Breakdown Voltage	_	700	_	-	V
I _{DSS}	Drain-Source Leakage Current	_	-	_	1	μA
RT						
V _{RT_REF}	Reference Voltage of RT pin	-	-	0.5	-	V
Current Sense						
V _{CS_CLAMP}	CS Clamp Voltage	-	-	1.6	-	V
V _{REF}	Internal Current Loop Control Reference	-	0.388	0.4	0.412	V
ton_min	Minimum t _{ON}	-	-	550	-	ns
ton_max	Maximum t _{ON}	$R_T = 51 k\Omega, V_{COMP} = 4V$	_	5.4	-	μs
toff_min	Minimum t _{OFF} (Note 7)	-	-	4	-	μs
toff_max	Maximum t _{OFF}	-	-	290	-	μs
FB						
V _{FB}	Feedback Voltage	-	3.7	3.95	4.18	V
I _{FB}	Feedback Pin Input Leakage Current	$V_{FB} = 2V$	-	4	-	μA
Error Amplifier						
G _M	G _M Trans-Conductance	-	-	25	-	μA/V
ISOURCE	Amplifier Source Current	$V_{CS} = 0V$	-	10	-	μA
Isink	Amplifier Sink Current	V _{CS} = 1.5V	-	28	-	μA
Thermal Foldback and	Over Temperature Protection (OTP)					
T _{FOLD}	Thermal Foldback (Note 7)	-	-	+145	-	°C
_	Thermal Shutdown (Notes7&8)	_	_	+160	_	°C

Notes:

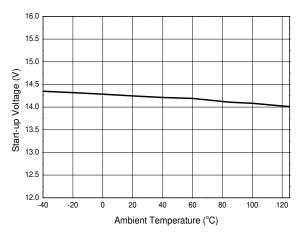
These parameters, although guaranteed by design, are not tested in production.
 The device will latch off when OTP happens, recovered after power cycle and the device won't operate normally at this temperature.

NEW PRODUCT

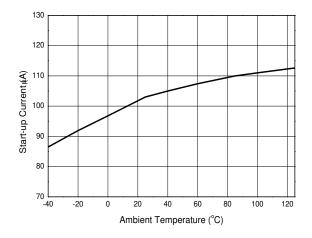


Performance Characteristics (Note 9)

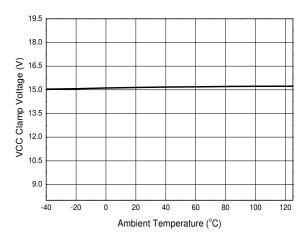
Start-Up Voltage Vs. Ambient Temperature

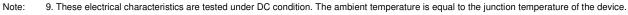


Start-up Current vs. Ambient Temperature

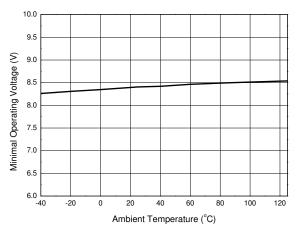


VCC Clamp Voltage vs. Ambient Temperature

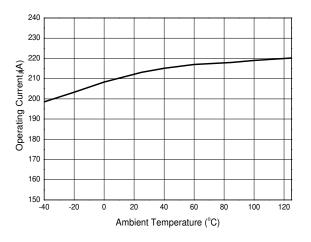




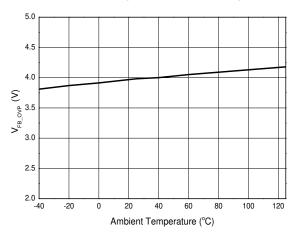
Minimum Operating Voltage Vs. Ambient Temperature



Operating Current vs. Ambient Temperature



Feedback voltage vs. Ambient Temperature





Functional Description and Application Information

Operation

The AL1692-10E is a single stage, single winding, high efficiency, and high power factor dimmable LED driver for triac dimmable LED lamp applications. The AL1692-10E integrates a 700V/1A high voltage MOSFET, and it can cover both 120Vac and 230Vac triac dimmable applications with eliminating external high voltage MOSFET and Varistor.

The AL1692-10E adopts source-driver technique to decrease the system operating current. It uses a novel method to detect the t_{OFF} time which results in the removal for the need of an auxiliary winding. The AL1692-10E operates at boundary conduction mode (BCM) which can ease EMI design and achieve high efficiency. High power factor (HPF) is achieved by using constant on-time mode. Coupled with a closed loop of constant current control, the AL1692-10E achieves good line and load regulation.

Start-up and Supply Voltage

Before start-up, the V_{CC} capacitor C4 is charged by the startup resistors (R2, R3) from the high voltage mains. When the start-up voltage is reached, the AL1692-10E starts switching. During normal operation, the V_{CC} supply is provided by start-up resisters (R2, R3) and the output voltage (V_{OUT}) rectified by one diode (D2). In this way the system can provide V_{CC} supply at low dimming angle.

The AL1692-10E has an internal VCC clamp voltage (typical 15.5V), which is limited by one internal active Zener diode.

When VCC voltage drops to below the $V_{OPR(MIN)}$, switching is stop. So the device can operate normally when the voltage on VCC pin is between $V_{OPR(MIN)}$ and VCC clamp voltage.

Protections

Under Voltage Lockout (UVLO)

When the voltage on the VCC pin drops to below $V_{OPR(Min)}$, the IC stops switching. The IC can restart when the voltage on VCC exceeds the startup voltage ($V_{TH(ST)}$).

Leading-Edge Blanking (LEB)

To prevent false detection of the peak current of the inductor, a blanking time following switch-on is designed. When the internal switch turns on, a short current spike can occur because of the capacitive discharge of the voltage over the drain and source. It is disregarded during the LEB time (t_{ON_MIN}) .

Cycle-by-cycle Over Current Protection (OCP)

The AL1692-10E has a built-in peak current detector. It triggers when the voltage on CS pin reaches the peak level V_{CS_CLAMP} . The R5 is connected to the CS pin to sense the current of the inductor. The maximum peak current ($I_{PEAK(MAX)}$)of the inductor can be calculated as below:

$$I_{PEAK(MAX)} = \frac{V_{CS_CLAMP}}{R5}$$

.....(1)

The detection circuit is activated after the LEB time. When the detection circuit sense the CS voltage is higher than 1V, the IC will turn off the switching to limit the output current. It automatically provides protection for the maximum LED current during operation. A propagation delay exists between over current detection and actual source-switch off, so the actual peak current is a little higher than the OCP level set by the R5.

Over-Voltage Protection and Output-Open Protection (OVP)

The output voltage is sensed by the FB pin, which provides an over-voltage protection (OVP) function. When the output is open or large transient happens, the output voltage will exceed the rated value (R8, R9). When the voltage exceeds V_{FB} , the over-voltage is triggered and the IC will discharge V_{CC} . When the V_{CC} is below the UVLO threshold voltage, IC will restart and the V_{CC} capacitor is charged again by start-up resistance. If the over voltage condition still exists, the system will work in hiccup mode.

Output-Short Protection (OSP)

When LED is shorted, the device cannot detect the toFF time, and the device controls the system operation at 4kHz low frequency.



Functional Description and Application Information (Cont.)

Thermal Foldback Protection (TFP)

The AL1692-10E has a thermal foldback protection (TFP) function and adopts self-adaptive control method, which can prevent the system breaking down caused by high temperature. The overheating temperature is set at +145°C typical, when the junction temperature of the IC is higher than +145°C typical, the device will linearly decrease the internal reference voltage to decrease the output current. As a result of this feature, the device can control the system's output power at high ambient temperature, to control the quantity of heat of the system. This enhances the safety of the system at high temperature.

Thermal foldback waveform is shown below:

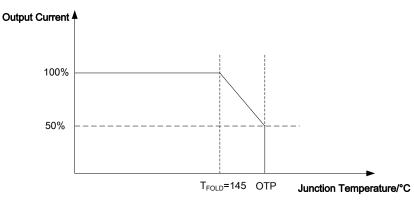


Figure. 1 Thermal Foldback Waveform

Over-Temperature Protection (OTP)

The AL1692-10E has over temperature protection (OTP) function. When the junction temperature reach to +160°C typical, the IC will trigger an over-temperature protection, which causes the device to shut down and latched condition. Once OTP triggered, the system need to be resumed after the system's AC source supply has been reset and power up.

Design Parameters

Setting the Current Sense Resistor R5

The AL1692-10E adopts boundary conduction mode, the output current is calculated as below,

$$I_{O_MEAN} = \frac{1}{\pi} \cdot \int_{0}^{\pi} \frac{1}{2} \cdot I_{PEAK} \cdot \frac{t_{OFF}}{t_{ON} + t_{OFF} + t_{DELAY}} dt$$

Where,

$$\begin{split} I_{\text{PEAK}} \text{ is the peak current of the inductance} \\ t_{\text{ON}} \text{ is the internal MOSFET on time} \\ t_{\text{OFF}} \text{ is the freewheel diode D1 conduction time} \\ t_{\text{DELAY}} \text{ is typical } 0.4 \mu \text{s} \end{split}$$

The AL1692-10E is a closed loop constant current control with the relationship between output current and current sense voltage follows this equation

$$V_{REF} = \frac{1}{\pi} \cdot \int_{0}^{\pi} I_{PEAK} \cdot \mathbf{R5} \cdot \frac{t_{OFF}}{t_{ON} + t_{OFF} + t_{DELAY}} dt$$

Where,

V_{REF} is the internal reference, typical 0.4V.

R5 is the current sense resistor

So we can get the output current equation as below,

$$I_{O_{MEAN}} = \frac{1}{2} \cdot \frac{V_{REF}}{R5}$$

AL1692-10E Document number: DS39670 Rev. 2 - 2 8 of 14 www.diodes.com



Functional Description and Application Information (Cont.)

Inductance Selection (L2)

In buck-boost structure, the peak current of the inductance can be calculated as below

$$I_{PEAK} = \frac{\pi \cdot V_{REF}}{R5 \cdot \int_{0}^{\pi} \sin(\theta) \cdot \frac{\sqrt{2} \cdot V_{IN_RMS} \cdot \sin(\theta)}{\sqrt{2} \cdot V_{IN_RMS} \cdot \sin(\theta) + Vo} d\theta}$$

Where,

VIN RMS is the input voltage's RMS value

V_O is the system output voltage

The AL1692-10E controls the system operating at boundary conduction mode which results in its operating frequency not being constant. To set the minimum switching frequency f_{MIN} at the crest of the minimum AC input.

$$L2 = \frac{\sqrt{2}V_{IN_RMS} \cdot V_O}{I_{PEAK} \cdot (\sqrt{2}V_{IN_RMS} + V_O) \cdot f_{MIN}}$$
(6)

According to the Faraday's Law, the winding number of the inductance can be calculated by:

$$N_{L2} = \frac{L2 \cdot I_{PEAK}}{A_e \cdot B_m}$$

Where,

Ae is the core effective area.

B_m is the maximum magnetic flux density.

ton_MAX Setting

In order to get a good dimmer compatibility and a good dimming depth, the device sets a t_{ON_MAX} by one external resistor R_T (R6). And the t_{ON_MAX} time has the below equation:

$$t_{ON_MAX} = \frac{3.3 \cdot C_{REF}}{\frac{V_{RT_REF}}{10 \cdot R6} + 0.33uA}$$

Where

 V_{RT_REF} is the internal RT pin 0.5V's reference. C_{REF} is the internal 1.5pF capacitor.

Dimming Control

The AL1692-10E is a closed loop control device; the dimming function is realized by t_{ON_MAX} limited when dimmer is connected in. When the dimmer is at the largest conduction angle, the device still has the adjustability to control the output current constant before COMP voltage is adjusted to the maximum 4V, so for most of the dimmer, the output current is almost the same with the no dimmer condition at the largest conduction angle. If the conduction angle is decreased, the COMP pin voltage will continue to increase quickly till to the maximum level (typical 4V), the device will output t_{ON_MAX} to limit system's output current. The t_{ON_MAX} is set by RT pin connected with one resistor, so the dimming depth can be adjusted by RT resistor (R6).

Before the AL1692-10E enters t_{ON_MAX} mode, it keeps the output current constant the same as no dimmer condition. When enter t_{ON_MAX} mode, we can get the following equation:

$$I_{PEAK_DIM} = \frac{V_{IN_RMS} \cdot Sin(\theta) \cdot t_{ON_MAX}}{L2}$$



Functional Description and Application Information (Cont.)

From the buck-boost output current equation, we can get the output current when dimming:

$$I_{O}(\theta) = \begin{cases} \frac{1}{2} \cdot \frac{V_{REF}}{R5} & \text{if } t_{ON} < t_{ON_MAX} \\ \frac{1}{\pi} \int_{0}^{\alpha} \frac{1}{2} \cdot I_{PEAK_DIM} \cdot \frac{\sqrt{2}V_{IN_RMS} \cdot Sin(\theta)}{\sqrt{2}V_{IN_RMS} \cdot Sin(\theta) + V_{O}} d\theta & else \end{cases}$$
(10)
Where,
$$\alpha \text{ is the dimmer conduction angle.}$$

٧

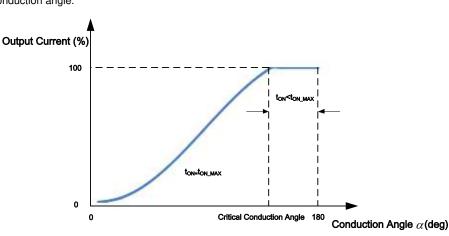


Figure.2 Dimming Curve

Dimmer Compatibility

Passive Bleeder Design

The passive bleeder is designed to supply latching and holding current to eliminate dimmer misfire and flicker.

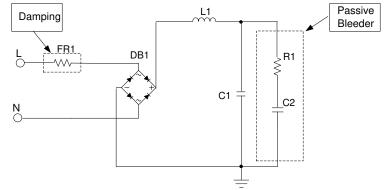


Figure.3 LED Driver Schematic with Passive Bleeder

The passive bleeder includes a capacitor (C2, in hundreds of nF) to provide latching current. A resistor (R1) is necessary to dampen the current spike. Because a large C2 will affect the PF, THD and efficiency, the value of the capacitor (C2) should be selected accordingly. Generally, 100nF/400V to 330nF/400V is recommended. R1 is used to limit the latching current, If R1 is too large, the latching current is not enough and the TRIAC dimmer will misfire causing LED flicker. If R1 is too small, it will result in greater power dissipation. Generally speaking, a 2000 to 2k0 resistor is selected for R1.

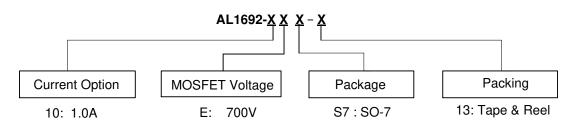
Passive Damping Design

FR1 is the damper for reducing the spike current caused by quick charging of C2 at firing. In General, FR1 is selected from 20Ω to 100Ω for low line like $120V_{AC}$ application, and 51Ω to 200Ω for high line like $230V_{AC}$ application.

NEW PRODUCT



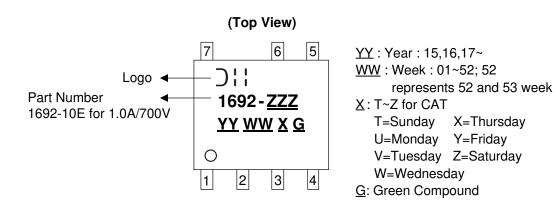
Ordering Information



Dout Number	Deskans Osda	Deskere	13" Tape	and Reel
Part Number	Package Code	Package	Quantity	Part Number Suffix
AL1692-10ES7-13	S7	SO-7	4000/Tape & Reel	-13

Marking Information

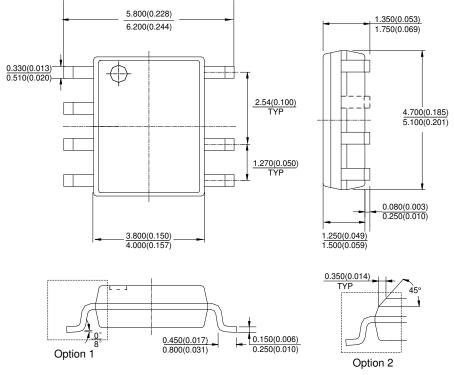
SO-7





Package Outline Dimensions (All dimensions in mm.)

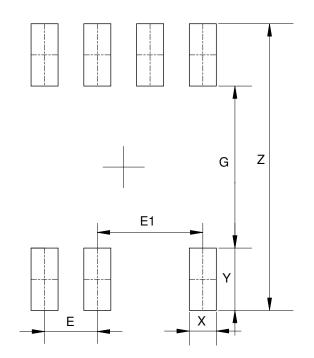
(1) Package Type: SO-7



Note: Eject hole, oriented hole and mold mark is optional.



(1) Package Type: SO-7



Dimensions	Z	G	Х	Y	E	E1
	(mm)/(inch)	(mm)/(inch)	(mm)/(inch)	(mm)/(inch)	(mm)/(inch)	(mm)/(inch)
Value	6.900/0.272	3.900/0.154	0.650/0.026	1.500/0.059	1.270/0.050	2.540/0.100

AL1692-10E



IMPORTANT NOTICE

DIODES INCORPORATED MAKES NO WARRANTY OF ANY KIND, EXPRESS OR IMPLIED, WITH REGARDS TO THIS DOCUMENT, INCLUDING, BUT NOT LIMITED TO, THE IMPLIED WARRANTIES OF MERCHANTABILITY AND FITNESS FOR A PARTICULAR PURPOSE (AND THEIR EQUIVALENTS UNDER THE LAWS OF ANY JURISDICTION).

Diodes Incorporated and its subsidiaries reserve the right to make modifications, enhancements, improvements, corrections or other changes without further notice to this document and any product described herein. Diodes Incorporated does not assume any liability arising out of the application or use of this document or any product described herein; neither does Diodes Incorporated convey any license under its patent or trademark rights, nor the rights of others. Any Customer or user of this document or products described herein in such applications shall assume all risks of such use and will agree to hold Diodes Incorporated and all the companies whose products are represented on Diodes Incorporated website, harmless against all damages.

Diodes Incorporated does not warrant or accept any liability whatsoever in respect of any products purchased through unauthorized sales channel. Should Customers purchase or use Diodes Incorporated products for any unintended or unauthorized application, Customers shall indemnify and hold Diodes Incorporated and its representatives harmless against all claims, damages, expenses, and attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized application.

Products described herein may be covered by one or more United States, international or foreign patents pending. Product names and markings noted herein may also be covered by one or more United States, international or foreign trademarks.

This document is written in English but may be translated into multiple languages for reference. Only the English version of this document is the final and determinative format released by Diodes Incorporated.

LIFE SUPPORT

Diodes Incorporated products are specifically not authorized for use as critical components in life support devices or systems without the express written approval of the Chief Executive Officer of Diodes Incorporated. As used herein:

- A. Life support devices or systems are devices or systems which:
 - 1. are intended to implant into the body, or
 - 2. support or sustain life and whose failure to perform when properly used in accordance with instructions for use provided in the labeling can be reasonably expected to result in significant injury to the user.
- B. A critical component is any component in a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or to affect its safety or effectiveness.

Customers represent that they have all necessary expertise in the safety and regulatory ramifications of their life support devices or systems, and acknowledge and agree that they are solely responsible for all legal, regulatory and safety-related requirements concerning their products and any use of Diodes Incorporated products in such safety-critical, life support devices or systems, notwithstanding any devices- or systems-related information or support that may be provided by Diodes Incorporated. Further, Customers must fully indemnify Diodes Incorporated and its representatives against any damages arising out of the use of Diodes Incorporated products in such safety-critical, life support devices or systems.

Copyright © 2017, Diodes Incorporated

www.diodes.com